# **General Multilayer Ceramic Capacitors**



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

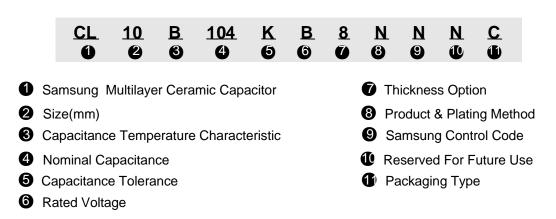
#### **General Features**

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

#### Applications

- General Electronic Circuit

#### **Part Numbering**



#### **1** Samsung Multilayer Ceramic Capacitor

### O SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0



Code	Temperature Characteristics				Temperature Range
С		COG	C	$0\pm30$ (ppm/ $^{\circ}\mathrm{C}$ )	
Р		P2H	P	$-150 \pm 60$	
R		R2H	R	-220±60	
S	Class	S2H	SA	-330±60	-55 ~ +125℃
т		T2H	TA	-470±60	
U		U2J	UA	-750±60	
L		S2L	SA	+350 ~ -1000	
Α		X5R	X5R	±15%	-55 ~ +85℃
В		X7R	X7R	±15%	-55 ~ +125℃
X	Class	X6S	X6S	±22%	-55 ~ +105℃
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃

### **O** CAPACITANCE TEMPERATURE CHARACTERISTIC

#### **\* Temperature Characteristic**

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
C∆	C0G	C0G	C0G	C0G
PΔ	-	P2J	P2H	P2H
RΔ	-	R2J	R2H	R2H
SΔ	-	S2J	S2H	S2H
ТΔ	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

### **O** NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits. The first and second digits identify the first and second significant figures of the capacitance. The third digit identifies the multiplier. 'R' identifies a decimal point.

# Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 µ F
104	100,000pF, 100nF, 0.1 µ F



# **G** CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	(mendang topi)
F	±1pF	
F	±1%	
G	±2%	
J	±5%	
K	±10%	More than 10pF
М	±20%	
Z	+80, -20%	

### **G** RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200 V
Q	6.3V	E	250V
Р	10V	G	500 V
0	16V	н	630V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	к	3,000V
С	100V		



#### SAMSUNG ELECTRO-MECHANICS

### **7** THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15	2220(5750)	н	1.6±0.20
	Y	1.25±0.20		I	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	Н	1.6±0.20			
	F	1.25±0.20			
	Н	1.6±0.20			
1210(3225)	I	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

### **③** PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

### **③** SAMSUNG CONTROL CODE

Code	Code Description of the code		Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC



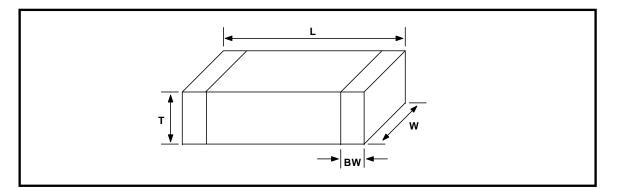
### **T** RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

### **()** PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
E	Embossing 7"		

# APPEARANCE AND DIMENSION



CODE	EIA CODE	DIMENSION ( mm )			
CODL		L	W	T (MAX)	BW
03	0201	$0.6~\pm~0.03$	$0.3~\pm~0.03$	0.33	$0.15~\pm~0.05$
05	0402	$1.0~\pm~0.05$	$0.5~\pm~0.05$	0.55	0.2 +0.15/-0.1
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2
21	0805	$2.0~\pm~0.1$	$1.25 \pm 0.1$	1.35	0.5 +0.2/-0.3
24	1006	$3.2 \pm 0.15$	1.6 ± 0.15	1.40	0.5 +0.2/-0.3
31	1206	$3.2 \pm 0.2$	1.6 ± 0.2	1.8	0.5 +0.3/-0.3
22	1010	$3.2~\pm~0.3$	$2.5~\pm~0.2$	2.7	
32	1210	$3.2 \pm 0.4$	$2.5~\pm~0.3$	2.8	$0.6 \pm 0.3$
43	1812	$4.5~\pm~0.4$	$3.2 \pm 0.3$	3.5	0.8 ± 0.3
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3



SAMSUNG ELECTRO-MECHANICS

NO	ITE	М	PERI	FORMANCE	TEST	TEST CONDITION								
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(×10)									
2	Insulation Resistance		10,000 $M_{\Omega}$ or 500 $M_{\Omega}$ - $\mu F$ whichever is smaller Rated Voltage is below 16V ; 10,000 $M_{\Omega}$ or 100 $M_{\Omega}$ - $\mu F$ whichever is smaller		Apply the Rated Voltage For 60 ~ 120 Sec.									
3	Withsta Volta		No Dielectric Breakdov Mechanical Breakdown		ClassI: 300% of the Rate ClassII:250% of the Rate with less than 50mA curren	d Voltage for 1~5								
					Capacitance	Frequency	Voltage							
		Class I	Within the specifie	d tolerance	≤ 1,000 pF	1111 ±1 0%	0.5 E.V.							
	Capacita	1			>1,000 pF	1kHz ±10%	0.5 ~ 5 Vrms							
4	nce				Capacitance	Frequency	Voltage							
		Class	Within the specifi	ed tolerance	≤ <b>10</b> <i>µ</i> F	1kHz ±10%	1.0±0.2Vrms							
		Π			>10 <i>µ</i> F	120Hz±20%	0.5±0.1 Vrms							
			Capacitance $\geq$ 30pF :	Q ≥ 1,000	Capacitance	Frequency	Voltage							
5	Q	Class I	< 30pF	: $Q \ge 400 + 20C$	≤ <b>1,000</b> pF	111 ±10%								
			( C	: Capacitance )	>1,000 pF	1kHz ±10%	0.5 ~ 5 Vrms							
			1. Characteristic : A()	(5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage							
			Rated Voltage	Spec	≤ 10 <i>μ</i> F	1k⊞ ±10%	1.0±0.2Vrms							
			≥25V	0.025 max	>10 <i>µ</i> F	120Hz±20%	0.5±0.1Vrms							
				16V	0.035 max	-								
								10V	0.05 max					
			2. Characteristic : F()	/5V)	1812 C≥47uF, 2220 All Low Profile Capa	0805 C≥4.7uF, 1206 C≥10uF, 1210 C≥22uF, 1812 C≥47uF, 2220 C≥100uF, All Low Profile Capacitors (P.16).								
6	Tan∂	Class	Rated Voltage	Spec	*2 0603 C≥0.47uF, 08 *3. 0402 C≥0.033uF, 06									
	i un o	П	50V	0.05 max, 0.07max* <sup>2</sup>	All 0805, 1206 size,		F							
			35V	0.07 max	*4 1210 C>6.8uF	, 1210 0 = 0.00								
			25V	0.05 max/ 0.07 max*³/ 0.09max*4	*5 0402 C≥0.22uF *6 All 1812 size									
			16V	0.09 max/ 0.125max*⁵										
			10V	0.125 max/ 0.16max*6										
			6.3V	0.16max	J									



SAMSUNG ELECTRO-MECHANICS

NO	ITE	PERFORMANCE			TEST CONDITION				
						Capacitance shall be measured by the steps			
					T 0 /// /	shown in the following table.			
			Characteris	stics	Temp. Coefficient (PPM/℃)	Step	Temp.(℃)		
			COG		$0 \pm 30$	1	25 ± 2		
			PH		-150 ± 60	<u></u>			
		Class	RH		-220 ± 60	2	Min. operating temp. $\pm$ 2		
		I	SH		-330 ± 60	3	25 ± 2		
			тн		-470 ± 60	4	Max. operating temp $\pm$ 2		
			UL		-750 ± 120	5	25 ± 2		
			SL		+350 ~ -1000	(1) Class I			
	_		L				Coefficient shall be calculated from		
_	Temperature					the formula a			
7	Characteristics of Capacitance					Temp, Coefficie	$nt = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$		
						C1; Capacita	ance at step 3		
					Capacitance Change	C2: Capacita	ance at 85 $^\circ C$		
			Characteri	istics	with No Bias	∆T: 60℃(=8	85℃-25℃)		
		Class	A(X5R) B(X7R	.)/ R)	$\pm$ 15%	(2) CLASS II			
		11	X(X6S)		±22%	Capacitance (	Change shall be calculated from the		
			F(Y5V	′)	+22% ~ -82%	formula as be	elow.		
							$\triangle C = \frac{C2 - C1}{C1} \times 100\%$		
							ance at step 3		
						ance at step 2 or 4			
							* Pressure for 10±1 sec.		
			No Indication Of Peeling Shall Occur On The			* 200g.f for 0201 case size.			
8	Adhesive	Strength							
0	of Termi	of Termination					<b>5</b> 00g.f		
							; 1mm		
		Apperance	No mechani	ical dam	nage shall occur.	Test speed ;			
			Character	ristics	Capacitance Change	4	board at the limit point in 5 sec.,		
				10100		Then measure	e capacitance.		
					Within $\pm$ 5% or $\pm$ 0.				
			Class	1	5 pF whichever is		20		
					larger		<u>R=230</u>		
9	Bending					50			
	Strength	Capacitance	1 1	A(X5R)/					
				B(X7R)/	Within $\pm$ 12.5%				
				X(X6S)		│ <b>│</b> ┥───┥	Bending limit		
			Class II			45±1	45±1		
				F(Y5V)	Within $\pm$ 30%				
				. ( )					



SAMSUNG ELECTRO-MECHANICS

ApperanceNo mechanical damage shall occur.Solder Temperature : 2'ApperanceNo mechanical damage shall occur.Dip Time : 10±1 sec.CharacteristicsCapacitance ChangeDip Time : 10±1 sec.Class I $\pm 0.25  pF$ whichever is largerEach termination shall the preheated as below :Capacitance $A(X5R)'$ B(X7R)Within ±7.5%Resistance toFWithin ±15%	C 235±5℃ RMA Type ec. 5±0.5 sec. 0℃ for 10~30 sec. 0±5℃			
10 Solder ability   10 Solder ability   Apperance No mechanical damage shall occur.   Dip Time 3±0.3 s   Pre-heating at 80-12   Dip Time 10±1 sec.   Each termination shall to preheated as below : Solder Temperature : 2'   Dip Time : 10±1 sec. Each termination shall to preheated as below :   Capacitance A(X5R)/ B(X7R) Within ±7.5%   Resistance to F Within ±15%   F Within ±20% Leave the capacitor in 5	RMA Type     ac.   5±0.5 sec.     0°C for 10~30 sec.     0°E 5°C     e fully immersed and     TIME(SEC.)			
10   Solderability   Image: Flux   <	ec. 5±0.5 sec. 0℃ for 10~30 sec. 0±5℃ e fully immersed and TIME(SEC.)			
Apperance   No mechanical damage shall occur.   Dip Time 3±0.3 s     Apperance   No mechanical damage shall occur.   Solder Temperature : 2'     Dip Time : 10±1 sec.   Dip Time : 10±1 sec.   Dip Time : 10±1 sec.     Capacitance   Class I   ±0.25 pF whichever is larger   Dip Time : 10±1 sec.     Capacitance   Class I   ±0.25 pF whichever is larger   STEP TEMP.(°C)     K(X6S)   Within ±7.5%   STEP TEMP.(°C)   1     K(X6S)   Within ±15%   Eave the capacitor in 5	ec. 5±0.5 sec. 0℃ for 10~30 sec. 0±5℃ e fully immersed and TIME(SEC.)			
ApperanceNo mechanical damage shall occur.Solder Temperature : 2'ApperanceNo mechanical damage shall occur.Dip Time : 10±1 sec.CharacteristicsCapacitance ChangeDip Time : 10±1 sec.Class I $\pm 0.25  pF$ whichever is largerEach termination shall the preheated as below :Capacitance $A(X5R)'$ B(X7R)Within ±7.5%Resistance toFWithin ±15%	0±5℃ e fully immersed and TIME(SEC.)			
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	e fully immersed and TIME(SEC.)			
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	TIME(SEC.)			
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	TIME(SEC.)			
Class I $\pm 0.25  \text{pr}$ whichever is largerSTEPTEMP.( $\mathbb{C}$ )Capacitance $A(X5R)'$ B(X7R)Within $\pm 7.5\%$ 180~100Class II $X(X6S)$ Within $\pm 15\%$ 2150~180FWithin $\pm 20\%$				
Capacitance     A(X5R)/ B(X7R)     Within ±7.5%     STEP     TEMP.(°C)       1     80~100     2     150~180       Resistance to     F     Within ±20%     Leave the capacitor in an and the capacitor in an an and the capacitor in an				
A(X5R)/ B(X7R)     Within ±7.5%     1     80~100       Class II     X(X6S)     Within ±15%     2     150~180       F     Within ±20%     Leave the capacitor in a				
Class II X(X6S) Within ±15% 2 150~180   Resistance to F Within ±20% Leave the capacitor in a second				
	60			
	ambient condition for			
11Soldering heatCapacitance $\geq 30 \text{pF}$ : Q $\geq 1000$ Specified time* before m	easurement			
(Class I) $(Class I)$ $(Class I)$	* 24 $\pm$ 2 hours (Class I)			
(C: Capacitance) 24 ± 2 hours (Class	1)			
Tan $\delta$ (Class II) Within the specified initial value				
Insulation Resistance Within the specified initial value				
Withstanding Voltage     Within the specified initial value				
Appearance No mechanical damage shall occur.				
Characteristics Capacitance Change				
Within ±2.5% or The capacitor shall be set to the set of the capacitor shall be set to the set of the	-			
larger 1.5mm changing freque	cy from 10Hz to 55Hz			
Capacitance A(X5R)/ B(X7R) Within ±5% and back to 10Hz In 1				
12 Test II X(X6S) Within ±10% Repeat this for 2hours of perpendicular directions	ach in 3 mutually			
F(Y5V) Within ±20%				
Q (Class I) Within the specified initial value				
Tan δ (Class Ⅱ) Within the specified initial value				
Insulation Resistance Within the specified initial value				





SAMSUNG ELECTRO-MECHANICS

**General Capacitors** 

NO	ITE	М	PERFORMANCE			TEST CONDITION			
		Appearance	No mechanical damage shall occur.		l occur.	Temperature : 40±2 ℃			
				cteristics	Capacitance Change	Relative humidity : 90~95 %RH			
			Class I		Within ±5.0% or ±0.5pF whichever is larger	Duration time : 500 +12/-0 hr.			
		Capacitance	Class	A(X5R)/ B(X7R)/ X(X6S)	Within ±12.5%	Leave the capacitor in ambient condition for specified time* before measurement.			
				F(Y5V)	Within ±30%	CLASS I : 24±2 Hr.			
			Capacitance	$\geq$ 30pF : Q $\geq$		CLASSⅡ : 24±2 Hr.			
10	Humidity	Q CLASS I	· ·		≥ 275 + 2.5×C				
13	(Steady State)		· ·	stic:A(X5R),	200 + 10×C (C: Capacitance) 2. Characteristic : F(Y5V)	_			
			0.05max (16)	,	0.075max (25V and over) 0.1max (16V, C<1.0µF)				
		Tan ∂	0.075max	- /	$0.125 \text{max}(16\text{V}, \text{C} \ge 1.0 \mu\text{F})$				
		CLASS II	(6.3V excep	t Table 1)	0.15 max (10 V)				
			0.125max*		0.195max (6.3V)				
			(refer to Tab	le 1)					
		Insulation Resistance	1,000 MΩ or	50MΩ•µF whichev	ver is smaller.				
		Appearance	No mechanic	al damage shal	l occur.	Applied Voltage : rated voltage			
			Chara	cteristics	Capacitance Change	Temperature : 40±2 ℃ Humidity : :90~95%RH			
		Capacitance	Class I		Within ±5.0% or ±0.5 $pF$ whichever is larger	Duration Time : 500 +12/-0 Hr. Charge/Discharge Current : 50 <sup>mA</sup> max.			
				A(X5R)/ B(X7R)/ X(X6S)	Within ±12.5% Within ±12.5% Within ±30%	Perform the initial measurement according to Note1.			
			Class II		Within ±30%	_			
				F(Y5V)	Within ±30%	Perform the final measurement according to Note2.			
14	Moisture Resistance	Q (Class I)	'	$\ge 30 \text{pF} : \text{Q} \ge 2$ <30 \text{pF} : \text{Q} \ge 10	00 00 + 10/3×C (C: Capacitance)	-			
			1. Characteri	stic:A(X5R), B(X7R)	2. Characteristic : F(Y5V)	-			
			0.05max (16) 0.075max (10	/ and over)	0.075max (25V and over) 0.1max (16V, C<1.0 $\mu$ <sup>T</sup> ) 0.125max(16V, C $\ge 1.0\mu$ <sup>T</sup> )				
		Tan ∂	0.075max						
		(Class Ⅱ)	(6.3V excep	t Table 1)	0.15max (10V)				
			0.125max* (refer to Tal	ble 1)	0.195max (6.3V)				
				nax (6.3V and b	pelow)	-			
		Insulation Resistance	500 MΩ or 25	5MΩ•μF whichever	r is smaller.				





#### SAMSUNG ELECTRO-MECHANICS

NO	ITE	Μ	PERFORMANCE				TEST CONDITION			
		Appearance	No mechanical damage shall occur.				Applied Voltage : 200%* of the rated voltage Temperature : max. operating temperature			
			Characteristics Capacitance Change				Duration Time : 1000 +48/-0 Hr.			
				_	Within ±3% or ±0.3 pF,	Charge/Dis	Charge/Discharge Current : 50mA max.			
			Class	s I	Whichever is larger					
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	* refer to table(3) : 150%/100% of the rated voltage			
			Class II	X(X6S)	Within ±25%	Perform th	e initial measurement	t according to		
					Within ±30%	Note1 for	Class II			
				F(Y5V)	Within ±30%	•				
			Capacitance	≥ <b>30</b> pF : C	Q ≥ 350					
		Q		-	F : Q ≥ 275 + 2.5×C	Note2.	e final measurement	according to		
		(Class I)	Capacitance	< 10pF :Q	$\geq$ 200 +10×C (C: Capacitance)	NOIEZ.				
	High		1. Characteri	istic : A(X5R	x), 2. Characteristic : F(Y5V)	-				
15	Temperature			B(X7R)	)					
	Resistance		0.05max		0.075max					
			(16V and o		(25V and over)					
		Tanδ (Class Ⅱ)	0.075max (1	0V)	0.1max(16V, C<1.0µF)					
			0.075max		0.125max(16V, C $\ge$ 1.0 $\mu$ F)					
			(6.3V excep	ot Table 1)	0.15max (10V)					
			0.125max* (refer to Ta	blo 1)	0.195max (6.3V)					
				ble I)						
			X(X6S) 0.11max (6.3V and below)							
		Insulation Resistance	1,000 № or	50MΩ•µF whic	chever is smaller.					
		Appearance	No mechanio	cal damage	shall occur.	Capacito	r shall be subjecte	d to 5 cycles.		
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :			
			Class	N T	Within ±2.5% or ±0.25 pF	Step	Temp.(℃)	Time(min.)		
			Uas:	<b>,</b> 1	Whichever is larger	_ 1	Min. operating	30		
		Capacitance		A(X5R)/	Within ±7.5%		temp.+0/-3			
			Class	B(X7R)/	Within ±7.5%	2	25	2~3		
16	Temperature		П	X(X6S)	Within ±15%	3	Max. operating	30		
	Cycle			F(Y5V)	Within ±20%		temp.+3/-0			
		Q	Within the s	necified initic		4	25	2~3		
		(Class I)				Leave the	e capacitor in amb	ient condition		
		Tan ∂	Within the s	nacified initic	مبادر اد	for specif	fied time* before m	neasurement		
		(Class Ⅱ)				* 24 ± 2 hours (Class I)				
		Insulation	Within the s	necified initia	al value	24 ± 2 hours (Class $II$ )				
		Resistance								



SAMSUNG ELECTRO-MECHANICS

### **RELIABILTY TEST CONDITION**

		Reco	ommended Sold	ering Method			
		Size	Temperature		Condition		
		inch (mm)	Characteristic	Capacitance	Flow	Reflow	
		0201 (0603)	-	-	-	0	
		0402 (1005)					
			Class I	-	0	0	
		0603 (1608)	Class II	$C < 1 \mu F$	0	0	
			Class II	$C \geq 1 \mu F$	-	0	
	Recommended Soldering Method By Size & Capacitance	0805 (2012)	Class I	-	0	0	
18			Class II	C < 4.7µF	0	0	
				$C \geq 4.7\mu F$	-	0	
			Array	-	-	0	
		1000 (0010)	Class I	-	0	0	
			Class II	C < 10 $\mu F$	0	0	
		1206 (3216)	Class II	$C \geq 10 \mu F$	-	0	
			Array	-	-	0	
		1210 (3225)				0	
		1808 (4520)	_			0	
		1812 (4532)	-	-	-	0	
		2220 (5750)				0	

Note1. Initial Measurement For Class  $\ensuremath{\mathbbm I}$ 

Perform the heat treatment at  $150\degree$ +0/- $10\degree$  for 1 hour. Then Leave the capacitor in ambient condition for  $48\pm4$  hours before measurement.

#### Note2. Latter Measurement

1. CLASS  ${\rm I}$ 

Leave the capacitor in ambient condition for  $24\pm 2$  hours before measurement

Then perform the measurement.

2. Class  ${\rm I\hspace{-0.1em}I}$ 

Perform the heat treatment at  $150\degree$ +0/- $10\degree$  for 1 hour. Then Leave the capacitor in ambient condition for  $48\pm4$  hours before measurement.

#### \*Table1.

Tan $\delta$	0.125max*
Class Ⅱ A(X5R), B(X7R)	$\begin{array}{llllllllllllllllllllllllllllllllllll$

*Table2.	
----------	--

*Table3	5.
---------	----

	High Temperature Resistance test						
	⊿C (Y5V)	± 30%					
		0402 C $\geq$ 0.47 $\mu$ F					
		0603 C $\geq$ 2.2 $\mu$ F					
	Class II	0805 C $\geq$ 4.7 $\mu$ F					
	F(Y5V)	1206 C $\geq$ 10.0 $\mu$ F					
	F(15V)	1210 C $\geq$ 22.0 $\mu$ F					
		1812 C $\geq$ 47.0 $\mu$ F					
		2220 C $\geq$ 100.0 $\mu$ F					
			I				

High Temperature Resistance test									
Applied Voltage	100% of the rated voltage	150% of the rated voltage							
Class Ⅱ A(X5R), B(X7R), X(X6S), F(Y5V)	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$\begin{array}{llllllllllllllllllllllllllllllllllll$							

Note3. All Size In Reliability Test Condition Section is "inch"

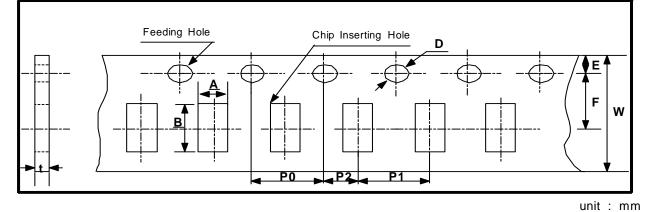


#### SAMSUNG S

SAMSUNG ELECTRO-MECHANICS

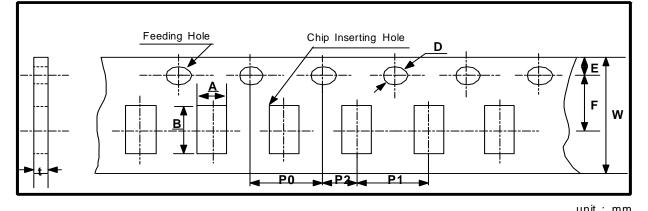
### PACKAGING

### CARDBOARD PAPER TAPE (4mm)



Symbol Α В w F Ε **P1** Ρ2 **P0** D t Туре D 0603 (1608) 1.1 1.9 i ±0.2 ±0.2 m е 0805 (2012) 1.6 2.4 8.0 3.5 1.75 4.0 2.0 4.0 Φ1.5 1.1 n ±0.2 ±0.2 ±0.3 ±0.05 ±0.1 ±0.1 ±0.05 ±0.1 +0.1/-0 Below s i 2.0 3.6 1206 (3216) ο ±0.2 ±0.2 n

### • CARDBOARD PAPER TAPE (2mm)



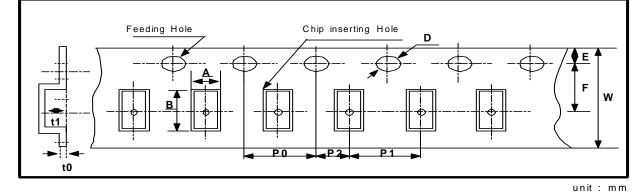
	ymbol Type	A	В	w	F	Е	P1	P2	P0	D	t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	3.5 ±0.05	1.75 ±0.1	2.0 ±0.05	2.0 ±0.05	±0.1	+0.1/-0.03	0.6 ±0.05



SAMSUNG ELECTRO-MECHANICS

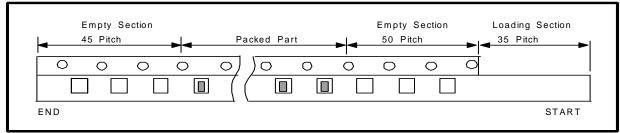
### PACKAGING

### EMBOSSED PLASTIC TAPE



-	/mbol Type	Α	В	w	F	E	P1	P 2	P 0	D	t1	t0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
Di	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

### TAPING SIZE



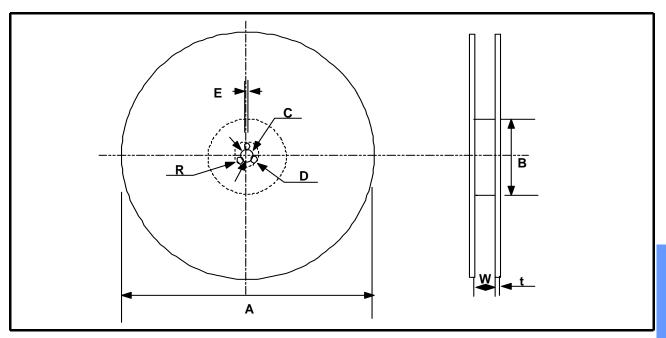
Туре	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000	-	All Size ≤3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0mm)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0mm)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{ mm})$ $1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	1210(3225),1808(4520) (t $\geq$ 2.0mm)	4,000
	L	0805(2012) (t≤0.85mm)	15,000 or 10,000(Option)		1812(4532)(t≤2.0mm)	4,000
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000



SAMSUNG ELECTRO-MECHANICS

# PACKAGING

### • REEL DIMENSION



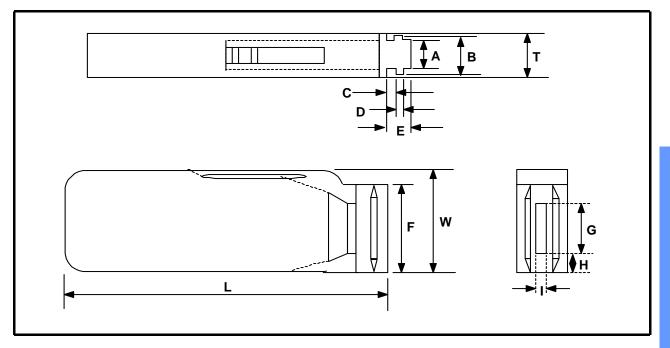
unit : mm

Symbol	Α	В	С	D	E	W	t	R
7" Reel	¢180+0/ -3	¢60+1/ -3			20105	0 4 5	1.2±0.2	1.0
13" Reel	\$330±2.0	ф80 <b>+</b> 1/ -3	\$13±0.3	25±0.5	$2.0\pm0.5$	9±1.5	2.2±0.2	1.0



### BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit : mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

### • QUANTITY OF BULK CASE PACKAGING

unit : pcs

Size	0402/4005)	06.02(16.08)	0805(2012)		
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm	
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000	

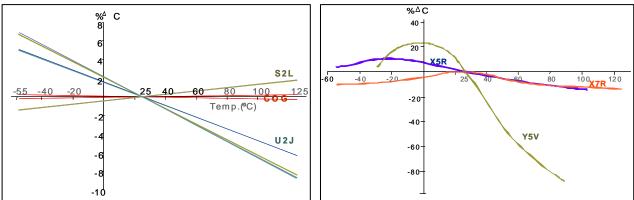


#### SAMSUNG ELECTRO-MECHANICS

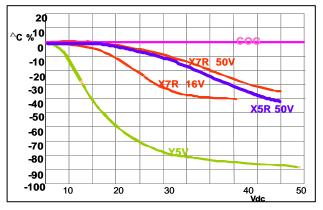
### **APPLICATION MANUAL**

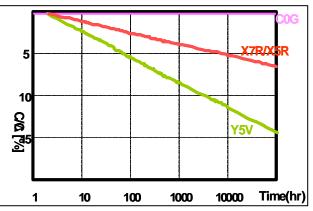
### ELECTRICAL CHARACTERISTICS

### ► CAPACITANCE - TEMPERATURE CHARACTERISTICS

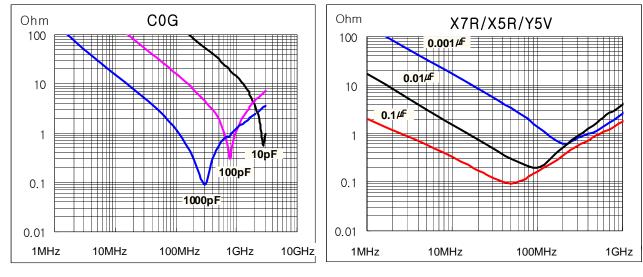


► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





#### ▶ IMPEDANCE - FREQUENCY CHARACTERISTICS





### STORAGE CONDITION

#### Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40  $^{\circ}$  and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

#### Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

#### Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

### DESIGN OF LAND PATTERN

When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

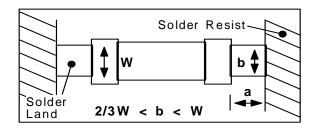
The amount of solder at the end terminations has a direct effect on the crack.

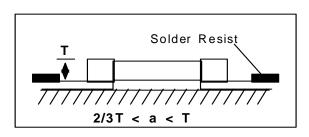
The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount

of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.







### ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

#### Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

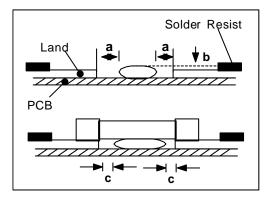
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

#### Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 <i>⊭</i> m	70~100 µm
С	> 0	> 0

### Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at  $160\,^\circ$ C or less, within 2 minutes or less.

### MOUNTING

#### Mounting Head Pressure

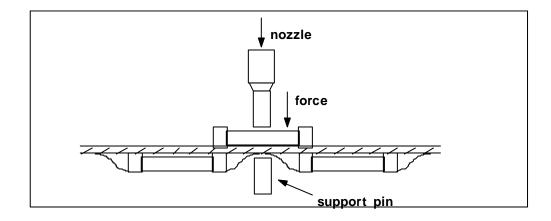
Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.



#### Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



#### Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors. The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

### Amount of Solder

Too much Solder	Cracks tend to occur due to large stress
Not enough Solder	Weak holding force may cause bad connections or detaching of the capacitor
Good	



### ► Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference( $\triangle$ T) must be less than 100 °C

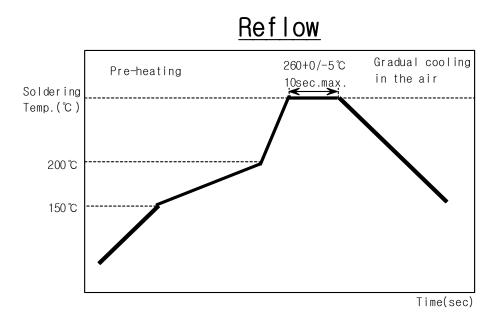
### Cleaning

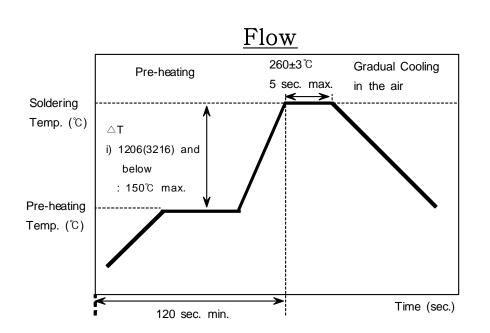
If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

### ▶ Notes for Separating Multiple, Shared PC Boards.

A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

### Recommended Soldering Profile





The Inside Edge

# Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (°C)	Time (Sec)	Time(Sec)	Time(Sec)
∆T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities					
Wattage	Tip Diameter	Soldering Time			
20W Max	3mm Max	4 Sec Max			

### \* Caution - Iron Tip Should Not Contact With Ceramic Body Directly.

SAMSUNG ELECTRO-MECHANICS

SAMSUNG

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Multilayer Ceramic Capacitors MLCC - SMD/SMT category:

Click to view products by Samsung manufacturer:

Other Similar products are found below :

M39014/01-1467 M39014/02-1218V M39014/02-1225V M39014/02-1262V M39014/02-1301 M39014/22-0631 1210J5000102JCT 1210J2K00102KXT 1210J5000103KXT 1210J5000223KXT D55342E07B379BR-TR D55342E07B523DR-T/R 1812J1K00103KXT 1812J1K00473KXT 1812J2K00680JCT 1812J4K00102MXT 1812J5000102JCT 1812J5000103JCT 1812J5000682JCT NIN-FB391JTRF NIN-FC2R7JTRF NPIS27H102MTRF C1206C101J1GAC C1608C0G1E472JT000N C2012C0G2A472J 2220J2K00101JCT KHC201E225M76N0T00 1812J1K00222JCT 1812J2K00102KXT 1812J2K00222KXT 1812J2K00472KXT 2-1622820-7-CUT-TAPE 2220J3K00102KXT 2225J2500824KXT CCR07CG103KM CGA2B2C0G1H010C CGA2B2C0G1H040C CGA2B2C0G1H050C CGA2B2C0G1H060D CGA2B2C0G1H070D CGA2B2C0G1H151J CGA2B2C0G1H1R5C CGA2B2C0G1H2R2C CGA2B2C0G1H3R3C CGA2B2C0G1H680J CGA2B2C0G1H6R8D CGA2B2X8R1H221K CGA2B2X8R1H472K CGA3E1X7R1C474K CGA3E2C0G1H561JT0Y0N